

Features

- Low RDS(on)
- Operated at Low Logic Level Gate Drive
- ESD Protected up to 3KV (HBM)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

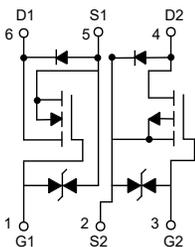
Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient^(Note 1)
-

Parameter	Symbol	Rating	Unit
Total Power Dissipation	P_D	1.25	W
N-Channel MOSFET			
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±12	V
Continuous Drain Current	I_D	1.3	A
Pulsed Drain Current ^(Note 2)	I_{DM}	5	A
P-Channel MOSFET			
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	±12	V
Continuous Drain Current	I_D	-1.1	A
Pulsed Drain Current ^(Note 2)	I_{DM}	-3.3	A

- Notes 1. Device Mounted on FR-4 Substrate PC Board, 2oz Copper, with 1in² Copper Plate.
2. Pulse Width Limited by Maximum Junction Temperature.

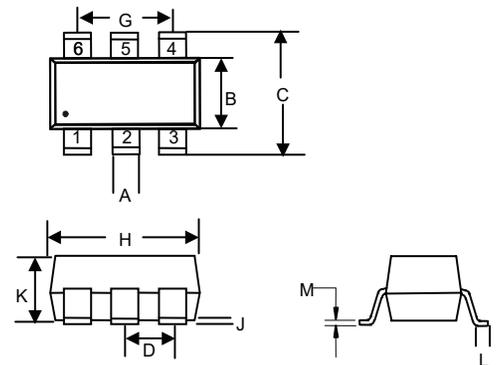
Internal Structure



Marking:49K

Dual N&P-Channel MOSFET

SOT23-6L



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.012	0.020	0.30	0.50	
B	0.051	0.070	1.30	1.80	
C	0.087	0.126	2.20	3.20	
D	0.037		0.95		TYP.
G	0.074		1.90		TYP.
H	0.106	0.122	2.70	3.10	
J	0.002	0.006	0.05	0.15	
K	0.030	0.051	0.75	1.30	
L	0.012	0.024	0.30	0.60	
M	0.003	0.008	0.08	0.22	

N-Channel MOSFET Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 10V$			± 10	μA
		$V_{DS}=0V, V_{GS}=\pm 4.5V$			± 1	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage ^(Note 3)	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.35	0.75	1.1	V
Drain-Source On-Resistance ^(Note 3)	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=0.65A$		190	380	m Ω
		$V_{GS}=2.5V, I_D=0.55A$		260	450	
		$V_{GS}=1.8V, I_D=0.45A$		390	800	
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=0.15A$			1.2	V
Forward Transconductance ^(Note 3)	g_{FS}	$V_{DS}=10V, I_D=0.8A$		1.6		S
Dynamic Characteristics^(Note 5)						
Input Capacitance	C_{iss}	$V_{DS}=16V, V_{GS}=0V, f=1MHz$		60		pF
Output Capacitance	C_{oss}			20		
Reverse Transfer Capacitance	C_{rss}			9		
Switching Characteristics^(Note 4,5)						
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=10V, V_{GS}=4.5V, I_D=500mA, R_{GEN}=10\Omega$		6.7		ns
Turn-On Rise Time	t_r			4.8		
Turn-Off Delay Time	$t_{d(off)}$			17.3		
Turn-Off Fall Time	t_f			7.4		

P-Channel MOSFET Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 10V$			± 10	μA
		$V_{DS}=0V, V_{GS}=\pm 4.5V$			± 1	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V$			-1	μA
Gate-Threshold Voltage ^(Note 3)	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.35	-0.60	-1.1	V
Drain-Source On-Resistance ^(Note 3)	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-1A$		450	520	m Ω
		$V_{GS}=-2.5V, I_D=-0.8A$		650	780	
		$V_{GS}=-1.8V, I_D=-0.5A$		950		
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=-0.5A$			-1.2	V
Forward Transconductance ^(Note 3)	g_{FS}	$V_{DS}=-10V, I_D=-0.54A$		1.2		S
Dynamic Characteristics^(Note 5)						
Input Capacitance	C_{iss}	$V_{DS}=-16V, V_{GS}=0V, f=1MHz$		175		
Output Capacitance	C_{oss}		21			
Reverse Transfer Capacitance	C_{rss}		8.7			
Switching Characteristics^(Note 4,5)						
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=-10V, V_{GS}=-4.5V$ $I_D=-200mA, R_{GEN}=10\Omega$		9		ns
Turn-On Rise Time	t_r		5.8			
Turn-Off Delay Time	$t_{d(off)}$		32.6			
Turn-Off Fall Time	t_f		20.3			

Note 3. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.

4. Switching characteristics are independent of operating junction temperature.

5. Guaranteed by Design, Not Subject to Production Testing.

Curve Characteristics(N-Channel)

Fig. 1 - Output Characteristics

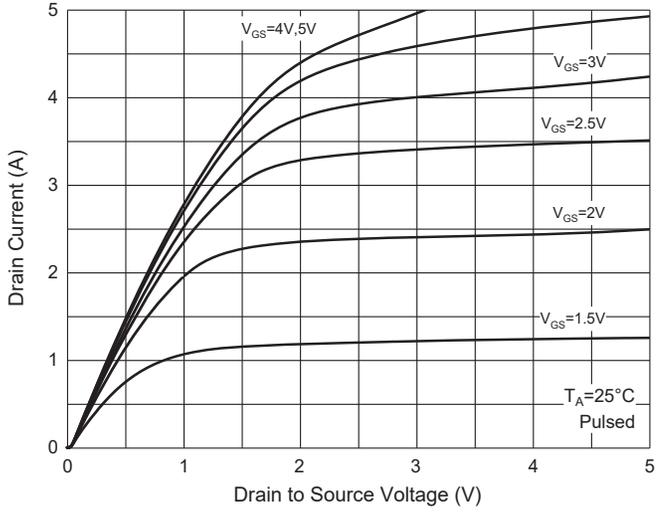


Fig. 2 - Transfer Characteristics

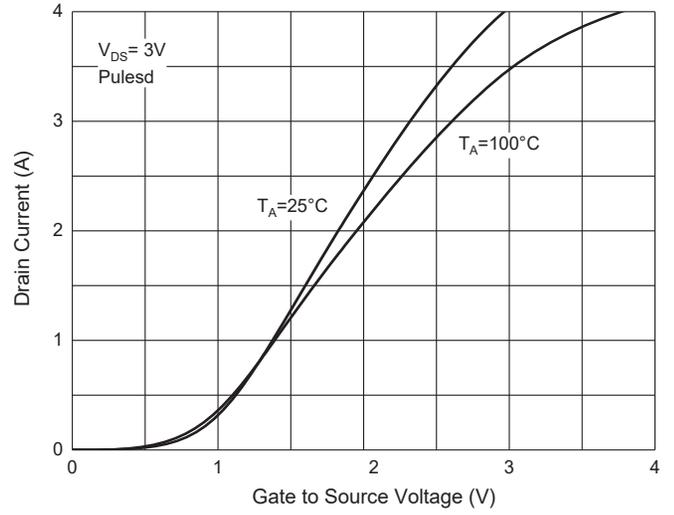


Fig. 3 - $R_{DS(ON)} - I_D$

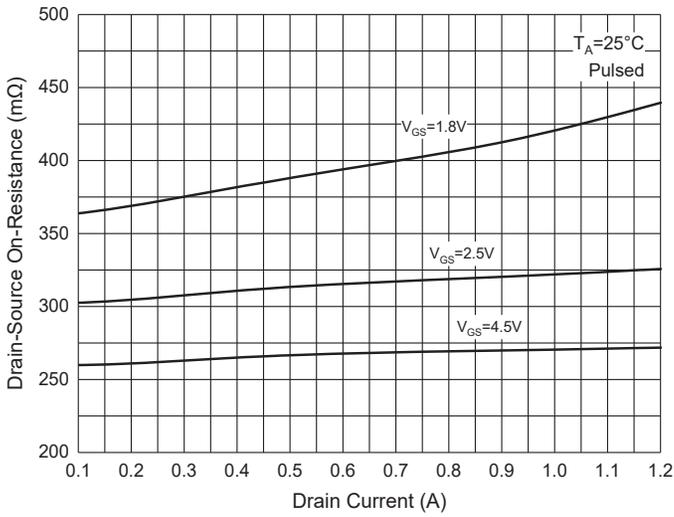


Fig. 4 - $R_{DS(ON)} - V_{GS}$

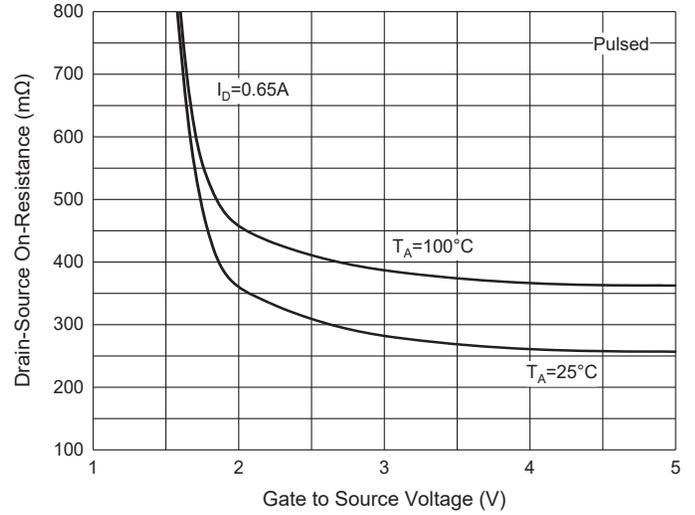


Fig. 5 - $I_S - V_{SD}$

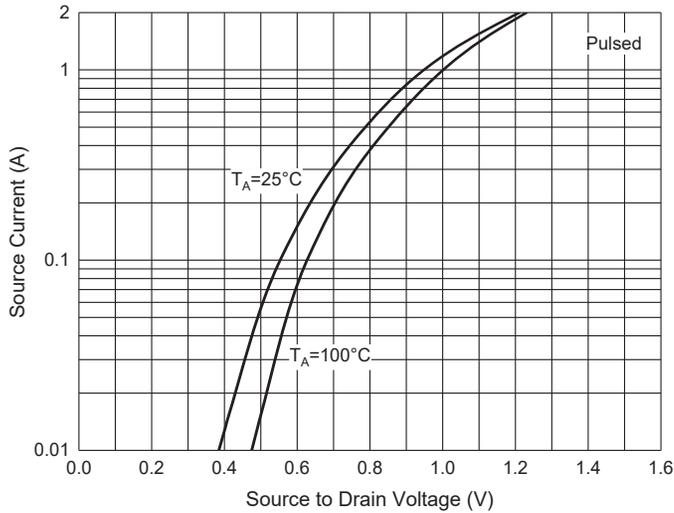
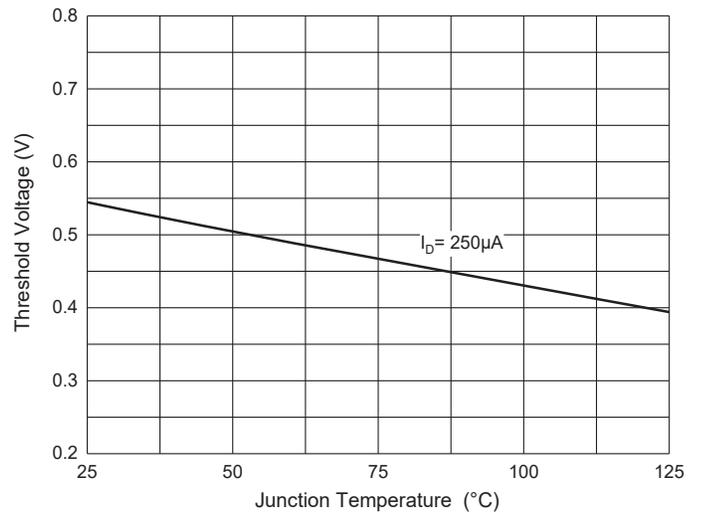
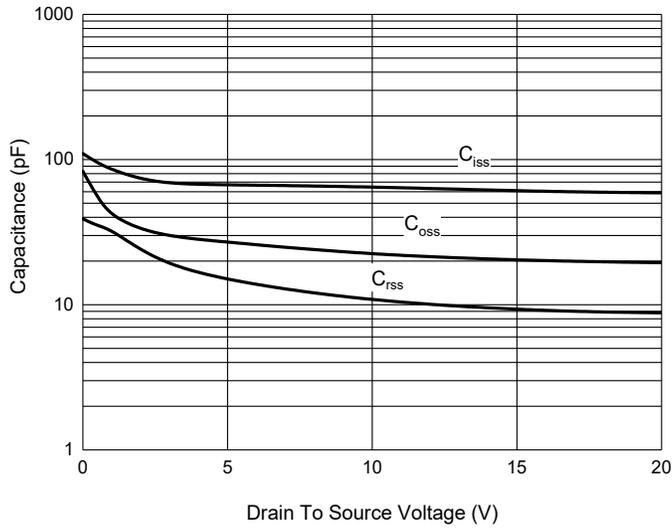


Fig. 6 - Threshold Voltage



Curve Characteristics(N-Channel)

Fig. 7 - Capacitance Characteristics



Curve Characteristics(P-Channel)

Fig. 8 - Output Characteristics

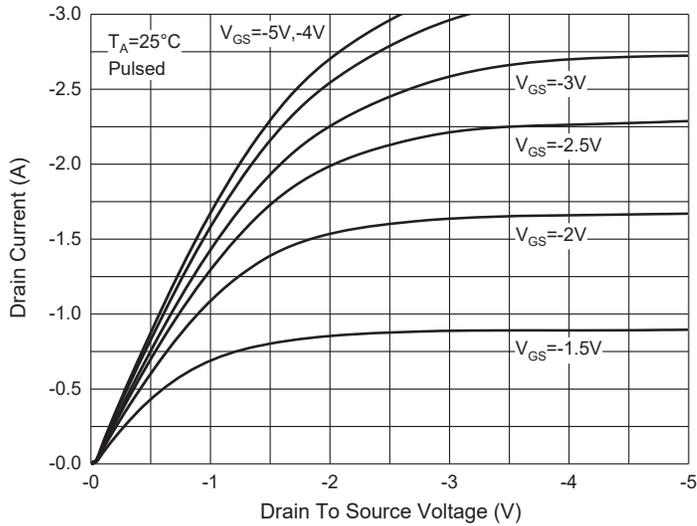
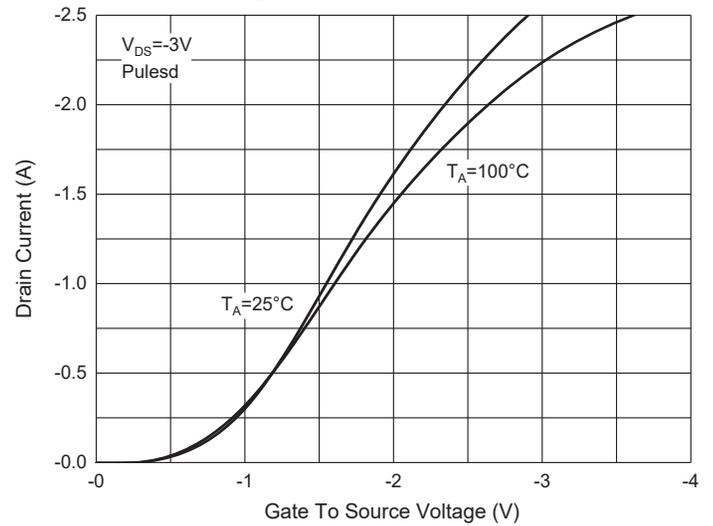


Fig. 9 - Transfer Characteristics



Curve Characteristics(P-Channel)

Fig. 10 - $R_{DS(ON)} - I_D$

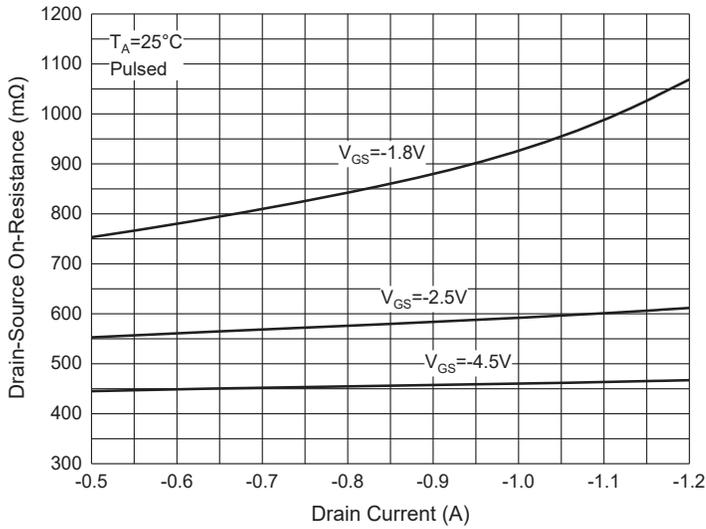


Fig. 11 - $R_{DS(ON)} - V_{GS}$

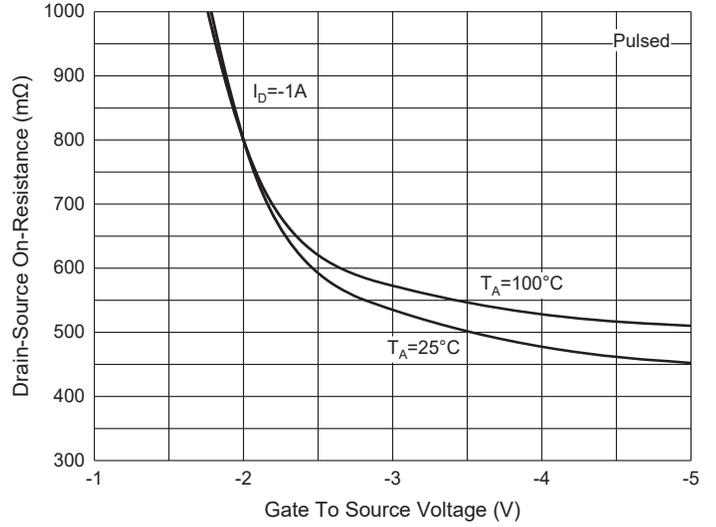


Fig. 12 - $I_S - V_{SD}$

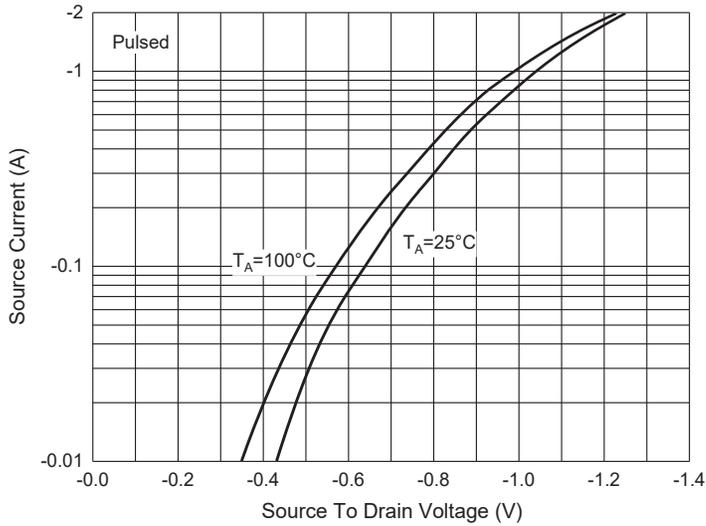


Fig. 13 - Threshold Voltage

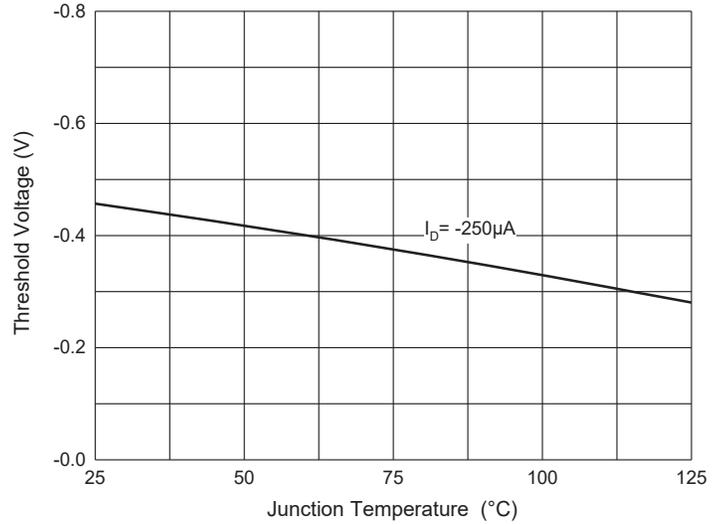
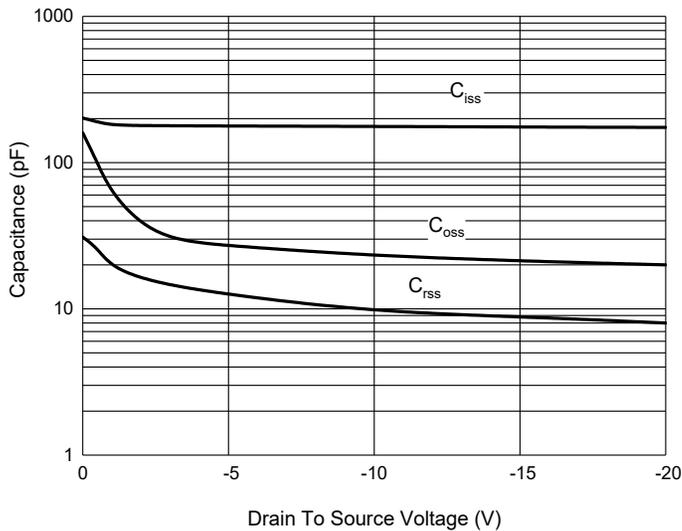


Fig. 14 - Capacitance Characteristics



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

Note : Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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